

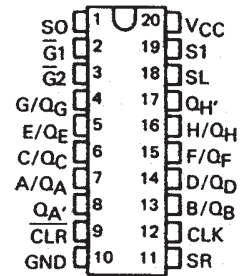
SN54LS299, SN54S299, SN74LS299, SN74S299 8-BIT UNIVERSAL SHIFT/STORAGE REGISTERS

SDLS156 – MARCH 1974 – REVISED MARCH 1988

- Multiplexed Inputs/Outputs Provide Improved Bit Density
- Four Modes of Operations:

Hold (Store)	Shift Left
Shift Right	Load Data
- Operates with Outputs Enabled or at High Z
- 3-State Outputs Drive Bus Lines Directly
- Can Be Cascaded for N-Bit Word Lengths
- SN54LS323 and SN74LS323 Are Similar But Have Synchronous Clear

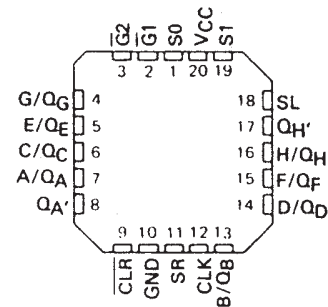
SN54LS299, SN54S299 . . . J OR W PACKAGE
SN74LS299, SN74S299 . . . DW OR N PACKAGE
(TOP VIEW)



- Applications:
 - Stacked or Push-Down Registers
 - Buffer Storage, and Accumulator Registers

TYPE	GUARANTEED	TYPICAL
	SHIFT (CLOCK) FREQUENCY	POWER DISSIPATION
'LS299	25 MHz	175 mW
'S299	50 MHz	700 mW

SN54LS299, SN54S299 . . . FK PACKAGE
(TOP VIEW)



description

These Schottky TTL eight-bit universal registers feature multiplexed inputs/outputs to achieve full eight-bit data handling in a single 20-pin package. Two function-select inputs and two output-control inputs can be used to choose the modes of operation listed in the function table.

Synchronous parallel loading is accomplished by taking both function-select lines, S0 and S1, high. This places the three-state outputs in a high-impedance state, which permits data that is applied on the input/output lines to be clocked into the register. Reading out of the register can be accomplished while the outputs are enabled in any mode. A direct overriding input is provided to clear the register whether the outputs are enabled or off.

FUNCTION TABLE

MODE	INPUTS						INPUTS/OUTPUTS								OUTPUTS			
	CLR	FUNCTION SELECT		OUTPUT CONTROL		CLK	SERIAL		A/QA	B/QB	C/QC	D/QD	E/QE	F/QF	G/QG	H/QH	QA'	QH'
		S1	S0	G1†	G2†		SL	SR										
Clear	L	X	L	L	L	X	X	X	L	L	L	L	L	L	L	L	L	L
	L	L	X	L	L	X	X	X	L	L	L	L	L	L	L	L	L	L
	L	H	H	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X
Hold	H	L	L	L	L	X	X	X	QA0	QB0	QC0	QD0	QE0	QF0	QG0	QH0	QA0	QH0
	H	X	X	L	L	L	X	X	QA0	QB0	QC0	QD0	QE0	QF0	QG0	QH0	QA0	QH0
Shift Right	H	L	H	L	L	†	X	H	H	QA _n	QB _n	QC _n	QD _n	QE _n	QF _n	QG _n	H	QH _n
	H	L	H	L	L	†	X	L	L	QA _n	QB _n	QC _n	QD _n	QE _n	QF _n	QG _n	L	QH _n
Shift Left	H	H	L	L	L	†	H	X	QB _n	QC _n	QD _n	QE _n	QF _n	QG _n	QH _n	H	QB _n	H
	H	H	L	L	L	†	L	X	QB _n	QC _n	QD _n	QE _n	QF _n	QG _n	QH _n	L	QB _n	L
Load	H	H	H	X	X	†	X	X	a	b	c	d	e	f	g	h	a	h

† When one or both output controls are high the eight input/output terminals are disabled to the high-impedance state; however, sequential operation or clearing of the register is not affected.

a . . . h = the level of the steady-state input at inputs A through H, respectively. These data are loaded into the flip-flops while the flip-flop outputs are isolated from the input/output terminals.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



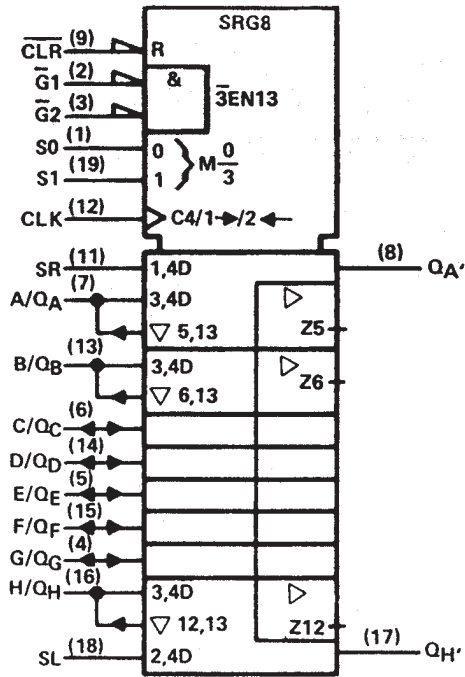
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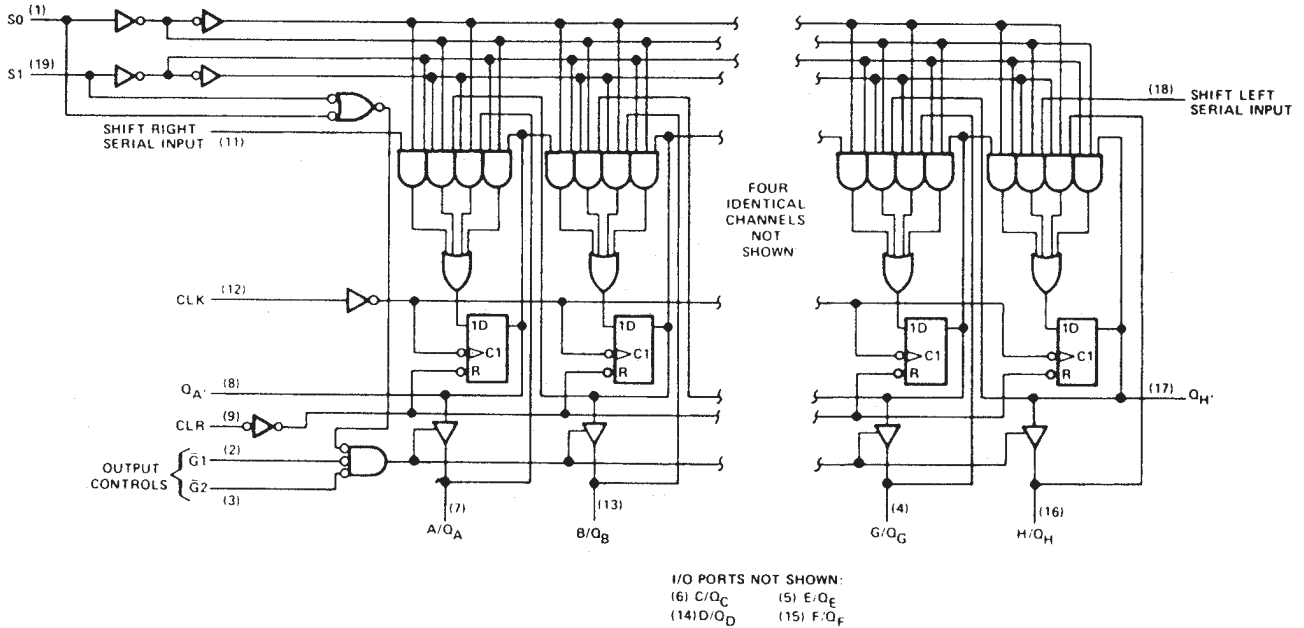
SDLS156 – MARCH 1974 – REVISED MARCH 1988

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for DW, J, N, and W packages.

logic diagram (positive logic)



Pin numbers shown are for DW, J, N, and W packages.



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SN54LS299, SN54S299, SN74LS299, SN74S299 8-BIT UNIVERSAL SHIFT/STORAGE REGISTERS

SDLS156 – MARCH 1974 – REVISED MARCH 1988

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	MIN	TYP‡	MAX	UNIT	
V _{IH}	High-level input voltage		2			V	
V _{IL}	Low-level input voltage				0.8	V	
V _{IK}	Input clamp voltage	V _{CC} = MIN, I _I = -18 mA			-1.2	V	
V _{OH}	High-level output voltage	Q _A thru Q _H	V _{CC} = MIN, V _{IH} = 2 V,	2.4	3.2	V	
		Q _A ' or Q _H '	V _{IL} = 0.8 V, I _{OH} = MAX	2.7	3.4		
V _{OL}	Low-level output voltage	V _{CC} = MIN, V _{IH} = 2 V, V _{IL} = 0.8 V, I _{OL} = MAX			0.5	V	
I _{OZH}	Off-state output current, high-level voltage applied	Q _A thru Q _H	V _{CC} = MAX, V _{IH} = 2 V, V _O = 2.4 V		100	μA	
I _{OZL}	Off-state output current, low-level voltage applied	Q _A thru Q _H	V _{CC} = MAX, V _{IH} = 2 V, V _O = 0.5 V		-250	μA	
I _I	Input current at maximum input voltage	V _{CC} = MAX, V _I = 5.5 V			1	mA	
I _{IH}	High-level input current	A thru H, S0, S1	V _{CC} = MAX, V _I = 2.7 V		100	μA	
		Any other			50		
I _{IL}	Low-level input current	CLK or CLR	V _{CC} = MAX, V _I = 0.5 V		-2	mA	
		S0, S1			-500	μA	
		Any other			-250	μA	
I _{OS}	Short-circuit output current §	Q _A thru Q _H	V _{CC} = MAX		-40	-100	mA
		Q _A ' or Q _H '			-20	-100	
I _{CC}	Supply current	V _{CC} = MAX		140	225	mA	

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time and duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER¶	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _{max}			See Note 2	50	70		MHz
t _{PLH}	CLK	Q _A ' or Q _H '	R _L = 1 kΩ, C _L = 15 pF		12	20	ns
t _{PHL}					13	20	
t _{PHL}	CLR	Q _A ' or Q _H '			14	21	ns
t _{PLH}	CLK	Q _A thru Q _H	R _L = 280 Ω, C _L = 45 pF		15	21	ns
t _{PHL}					15	21	
t _{PHL}	G1, G2	Q _A thru Q _H	R _L = 280 Ω, C _L = 45 pF		16	24	ns
t _{PZH}					10	18	
t _{PZL}	G1, G2	Q _A thru Q _H	R _L = 280 Ω, C _L = 5 pF		12	18	ns
t _{PHZ}					7	12	
t _{PLZ}	G1, G2	Q _A thru Q _H	R _L = 280 Ω, C _L = 5 pF		7	12	ns
t _{PLZ}					7	12	

¶ f_{max} = maximum clock frequency

t_{PLH} = Propagation delay time, low-to-high-level output

t_{PHL} = Propagation delay time, high-to-low-level output

t_{PZH} = output enable time to high level

t_{PZL} = output enable time to low level

t_{PHZ} = output disable time from high level

t_{PLZ} = output disable time from low level

NOTE 2: For testing f_{max}, all outputs are loaded simultaneously, each with C_L and R_L as specified for the propagation times.

Load circuits and voltage waveforms are shown in Section 1.



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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
78024012A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Level-NC-NC-NC
7802401RA	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
7802401RA	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
7802401SA	ACTIVE	CFP	W	20	1	TBD	Call TI	Level-NC-NC-NC
7802401SA	ACTIVE	CFP	W	20	1	TBD	Call TI	Level-NC-NC-NC
SN54LS299J	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
SN54LS299J	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
SN54S299J	LIFEBUY	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
SN54S299J	LIFEBUY	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
SN74LS299DW	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299DW	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299DWE4	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299DWE4	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299DWR	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299DWR	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299DWRE4	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299DWRE4	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74LS299N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN74LS299N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN74LS299NE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN74LS299NE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN74S299DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI
SN74S299DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI
SN74S299DWR	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI
SN74S299DWR	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI
SN74S299N	OBSOLETE	PDIP	N	20		TBD	Call TI	Call TI
SN74S299N	OBSOLETE	PDIP	N	20		TBD	Call TI	Call TI
SN74S299N3	OBSOLETE	PDIP	N	20		TBD	Call TI	Call TI
SN74S299N3	OBSOLETE	PDIP	N	20		TBD	Call TI	Call TI
SNJ54LS299FK	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Level-NC-NC-NC
SNJ54LS299FK	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Level-NC-NC-NC
SNJ54LS299J	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
SNJ54LS299J	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
SNJ54LS299W	ACTIVE	CFP	W	20	1	TBD	Call TI	Level-NC-NC-NC